

L Number	Hits	Search Text	DB	Time stamp
-	2	("6162715").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/21 11:53
-	23	(tungsten adj nitride or "WN.sub.x") with (passivating or passivation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/22 08:35
-	414	monomethyl adj hydrazine or "MMH"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/22 07:00
-	407	(tungsten adj nitride or "WN.sub.x") with (copper or "cu")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/22 08:37
-	64	capacitor and (tungsten adj nitride or "WN.sub.x") with (copper or "cu")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/22 08:37

L Number	Hits	Search Text	DB	Time stamp
-	4640153	conductive or metal or tungsten or polysilicon or aluminum or ferroelectric or tungsten adj nitride or "W" or "WN" or "WN.sub.x"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:28
-	9561	diborane or ("b.sub.2" adj "h.sub.6") or "b.sub.2h.sub.6"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:05
-	39933	phosphine or "ph.sub.3"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:09
-	1226	methylsilane or ("ch.sub.3" adj "si" adj "h.sub.3") or ("ch.sub.3" adjl "sih.sub.3") or "ch.sub.3sih.sub.3"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:12
-	1226	methylsilane or ("ch.sub.3" adjl "si" adjl "h.sub.3") or ("ch.sub.3" adjl "sih.sub.3") or "ch.sub.3sih.sub.3"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:39
-	485	hexamethyldisilane	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:22
-	2245	(diborane or ("b.sub.2" adj "h.sub.6") or "b.sub.2h.sub.6") with (conductive or metal or tungsten or polysilicon or aluminum or ferroelectric or tungsten adj nitride or "W" or "WN" or "WN.sub.x")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:26
-	6080	(phosphine or "ph.sub.3") with (conductive or metal or tungsten or polysilicon or aluminum or ferroelectric or tungsten adj nitride or "W" or "WN" or "WN.sub.x")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:26
-	63	(methylsilane or ("ch.sub.3" adjl "si" adjl "h.sub.3") or ("ch.sub.3" adjl "sih.sub.3") or "ch.sub.3sih.sub.3") with (conductive or metal or tungsten or polysilicon or aluminum or ferroelectric or tungsten adj nitride or "W" or "WN" or "WN.sub.x")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:27
-	9960	tantalum adj (oxide or pentoxide) or ("ta.sub.2" adjl "O.sub. 5") or "ta.sub.2o.sub.5"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:30
-	6781	tungsten adj nitride or WN or "WN.sub.x"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:31
-	0	(diborane or ("b.sub.2" adj "h.sub.6") or "b.sub.2h.sub.6") with (tantalum adj (oxide or pentoxide) or ("ta.sub.2" adjl "O.sub. 5") or "ta.sub.2o.sub.5")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:34
-	0	(methylsilane or ("ch.sub.3" adjl "si" adjl "h.sub.3") or ("ch.sub.3" adjl "sih.sub.3") or "ch.sub.3sih.sub.3") with (tantalum adj (oxide or pentoxide) or ("ta.sub.2" adjl "O.sub. 5") or "ta.sub.2o.sub.5")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:34

-	5	(phosphine or "ph.sub.3") with (tantalum adj (oxide or pentoxide) or ("ta.sub.2" adjl "O.sub. 5") or "ta.sub.2o.sub.5")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:34
-	0	(methylsilane or ("ch.sub.3" adjl "si" adjl "h.sub.3") or ("ch.sub.3" adjl "sih.sub.3") or "ch.sub.3sih.sub.3") with (tungsten adj nitride or WN or "WN.sub.x")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:34
-	3	(diborane or ("b.sub.2" adj "h.sub.6") or "b.sub.2h.sub.6") with (tungsten adj nitride or WN or "WN.sub.x")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:38
-	2	(phosphine or "ph.sub.3") with (tungsten adj nitride or WN or "WN.sub.x")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:37
-	6	(methylsilane or ("ch.sub.3" adjl "si" adjl "h.sub.3") or ("ch.sub.3" adjl "sih.sub.3") or "ch.sub.3sih.sub.3") with conductive	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:39